

S200 - 50

200 Watts, 50 Volts, Class AB Milcom 1.5 - 30 MHz

GENERAL DESCRIPT The S200-50 is a COMMON EMITTE operation from a 50 Volts supply. It n The device exhibits excellent linearity	CASE OUTLINE 55HX, Style 2	
ABSOLUTE MAXIMU Maximum Power Dissipation @ 25°C	MRATINGS 320 Watts	
Maximum Voltage and Current		
BVces Collector to Emiter Voltage	100 Volts	
BVebo Emitter to Base Voltage	4.0 Volts	
Ic Collector Current	30 A	
Maximum Temperatures		
Storage Temperature	- 65 to +150°C	
Operating Junction Temperature	+150°C	

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Pout Pin Pg ηc VSWR	Power Output Power Input Power Gain Efficiency Load Mismatch Tolerance	F = 30 MHz Vcc = 50 Volts	200 12	14.5 60	12 30:1	Watts Watts dB %

BVebo BVces BVceo Cob h _{FE} θjc	Emitter to Base Breakdown Collector to Emitter Breakdown Collector to Emitter Breakdown Output Capacitance DC - Current Gain Thermal Resistance	Ie = 20 mA Ic = 100 mA Ie = 200 mA Vcb = 50V , F = 1 MHz Vce = 5 V , Ic = 1 A	4.0 110 70 10	300	.55	Volts Volts Volts pF °C/W
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